

BT155W-1200T

Rev.02 - 30 July 2019

SCR

Product data sheet

1. General description

Planar passivated Silicon Controlled Rectifier in a TO247 plastic package intended for use in applications requiring very high inrush current capability and high thermal cycling performance.

2. Features and benefits

- High thermal cycling performance
- Planar passivated for voltage ruggedness and reliability
- High voltage capacity •
- Very high current surge capability

3. Applications

- Line rectifying 50/60 Hz •
- Softstart AC motor control
- DC Motor control •
- Power converter •
- AC power control •
- Lighting and temperature control • •
- Uninterruptible Power Supply (UPS)
- Solid State Relay (SSR)
- Traction battery charging

4. Quick reference data

Fable 1. Quick reference data							
Symbol	Parameter	Conditions	Values	Unit			
Absolute	Absolute maximum rating						
V_{DRM}	repetitive peak off-state voltage		1200	V			
V_{RRM}	repetitive peak reverse voltage		1200	V			
I _{T(RMS)}	RMS on-state current	half sine wave; T _{mb} ≤ 131 °C; <u>Fig. 1</u> ; <u>Fig. 2; Fig. 3</u>	79	A			
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; t_p = 10 ms; Fig. 4; Fig. 5	650	A			
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms	715	А			
T _j	junction temperature		150	°C			

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Symbol	Parameter	Conditions			Тур	Max	Unit	
Static ch	Static characteristics							
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 7; Fig. 8</u>		-	-	50	mA	
Dynamic	Dynamic characteristics							
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 804 V; T _j = 125 °C; R _{GK} = 100 Ω; (V_{DM} = 67% of V_{DRM}); exponential waveform		1500	-	-	V/µs	

5. Pinning information . .

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode		
2	A	anode		A H K G
3	G	gate		sym037
mb	A	mounting base; connected to anode		

6. Ordering information

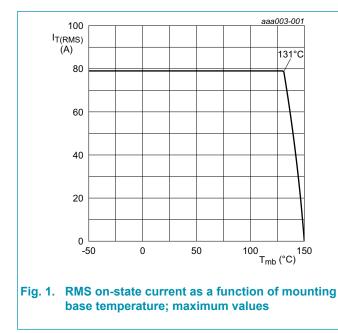
Table 3. Ordering information								
Type number	Package	Orderable part number	Packing	Small packing	Package	Package		
	Name		method	quantity	version	issue date		
BT155W-1200T	TO247	BT155W-1200TQ	Tube	30	TO247N	20-July-2016		

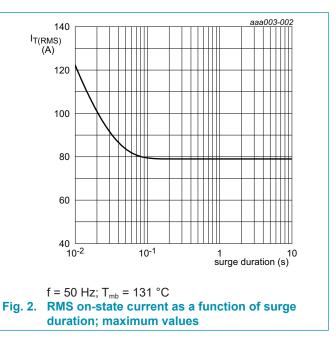
7. Limiting values

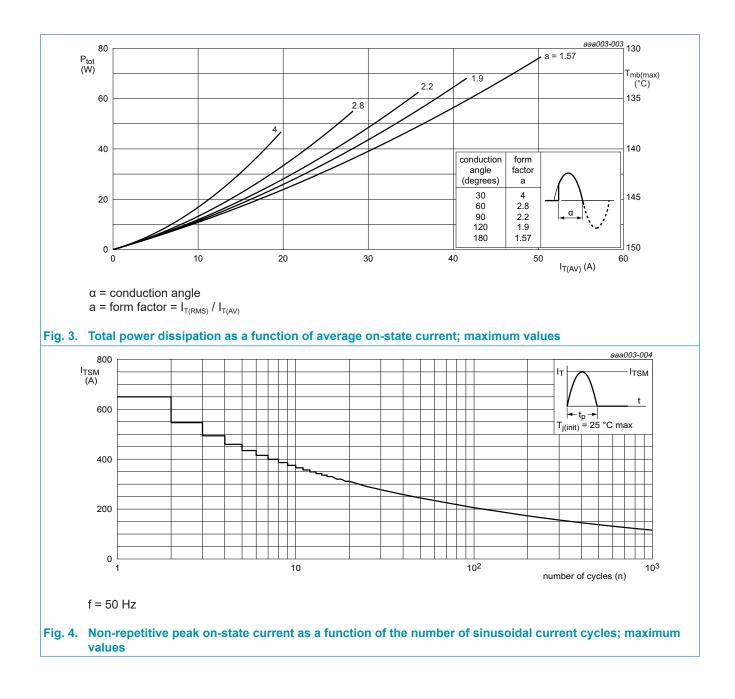
Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{DRM}	repetitive peak off-state voltage		1200	V
V_{RRM}	repetitive peak reverse voltage		1200	V
$I_{T(AV)}$	average on-state current	half sine wave; T _{mb} ≤ 131 °C	50	А
$\mathbf{I}_{\mathrm{T}(\mathrm{RMS})}$	RMS on-state current	half sine wave; T _{mb} ≤ 131 °C; <u>Fig 1; Fig 2</u> ; <u>Fig 3</u>	79	A
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; t_p = 10 ms; Fig 4; Fig 5	650	A
		half sine wave; $T_{j(init)}$ = 25 °C; t_p = 8.3 ms	715	А
l ² t	l ² t for fusing	t _p = 10 ms; sine-wave pulse	2113	A ² s
dl _⊤ /dt	rate of rise of on-state current	I _G = 200mA	150	A/µs
I _{GM}	peak gate current		8	А
V_{RGM}	peak reverse gate voltage		5	V
P_{GM}	peak gate power		20	W
$P_{G(AV)}$	average gate power	over any 20 ms period	1	W
T _{stg}	storage temperature		-40 to 150	°C
Tj	junction temperature		150	°C







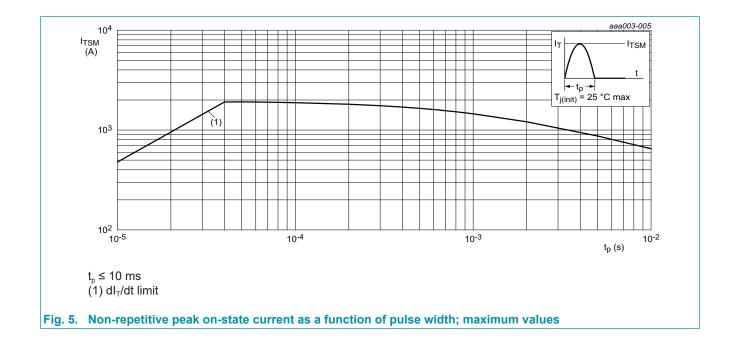
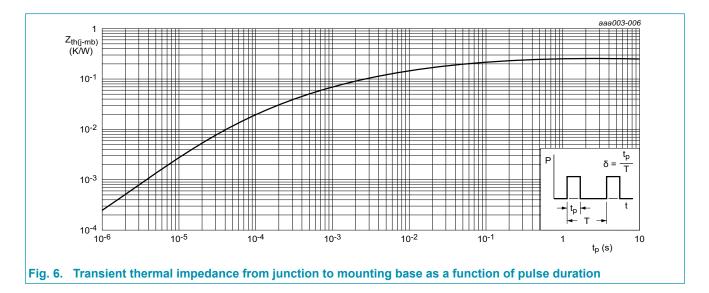


Table 5.	Thermal	&	Mechanical	characteristics
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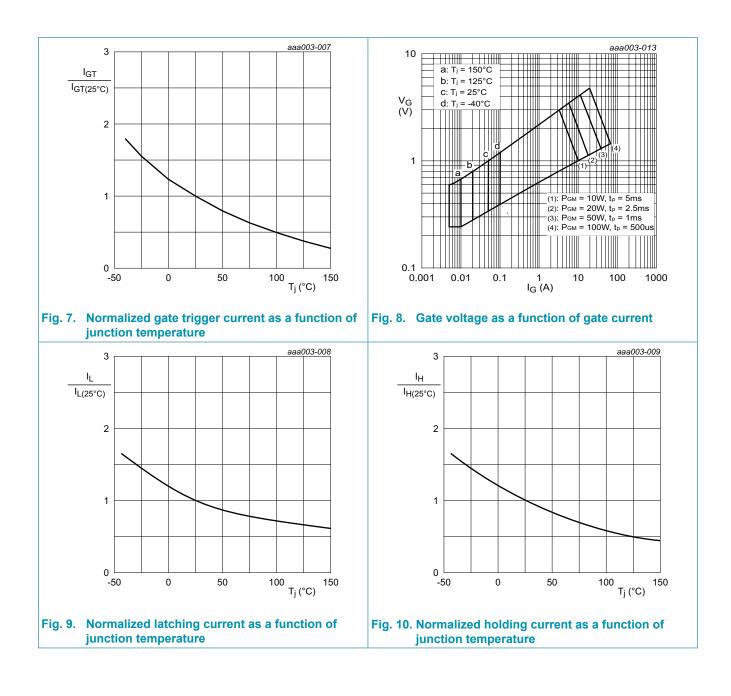
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance from junction to mounting base	<u>Fig 6</u>	-	-	0.25	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	50	-	K/W
	Mounting torque	M3 screw mounting	0.55	-	0.8	Nm

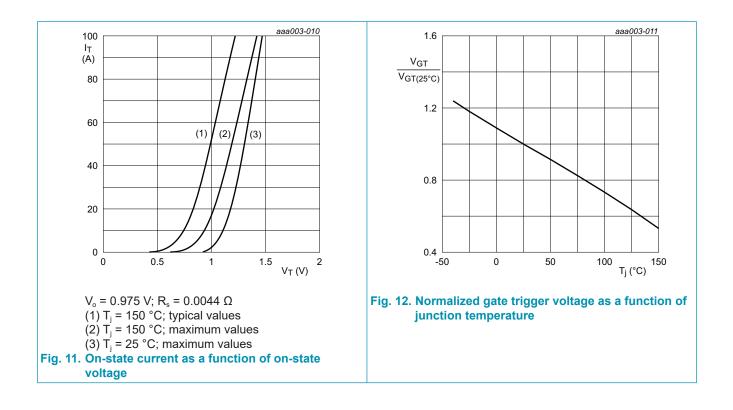
Note: It is recommended that a metal washer is inserted between screw head and mounting tab. Do not use self-tapping screws.



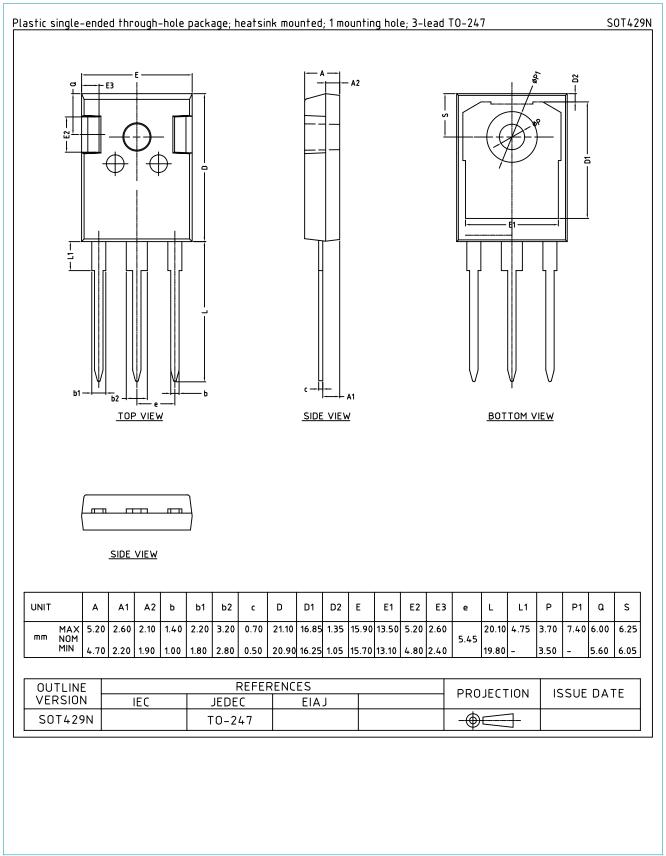
9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics	·				
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 7; Fig. 8	-	-	50	mA
I _L	latching current	$V_{\rm D}$ = 12 V; I _G = 0.1 A; T _j = 25 °C; Fig. 9	-	-	300	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 10</u>	-	-	200	mA
V _T	on-state voltage	I _T = 50 A; T _j = 25 °C; <u>Fig. 11</u>	-	-	1.3	V
		I _T = 90 A; T _j = 25 °C; <u>Fig. 11</u>	-	-	1.5	V
V _{GT} gate trigger voltage		$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T}_{j} = 25 \text{ °C};$ Fig. 12	-	0.7	1	V
		V _D = 800 V; I _T = 0.1 A; T _j = 125 °C	0.25	0.4	-	V
I _D	off-state current	V _D = 1200 V; T _j = 125 °C	-	-	3	mA
I _R	reverse current	V _D = 1200 V; T _j = 125 °C	-	-	3	mA
Dynamic	characteristics	· · · · ·				
dV _D /dt rate of rise of off-state voltage			1500	-	-	V/µs
		V_{DM} = 804 V; T _j = 150 °C; R _{GK} = 100 Ω; (V_{DM} = 67% of V_{DRM}); exponential waveform	1000	-	-	V/µs
t _{gt}	gate-controlled turn-on time	$ \begin{array}{l} {I_{\text{TM}}} = 40 \text{ A}; V_{\text{D}} = 800 \text{V}; {I_{\text{G}}} = 0.1 \text{A}; \text{d} {I_{\text{G}}} \text{/} \\ \text{d} t = 5 \text{A} \text{/} \mu \text{s}; \text{T}_{\text{j}} = 25 ^{\circ} \text{C} \end{array} $	-	2	-	μs
t _q	commutated turn-off time		-	150	-	μs





10. Package outline



11. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <u>http://www.ween-semi.com</u>.

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